





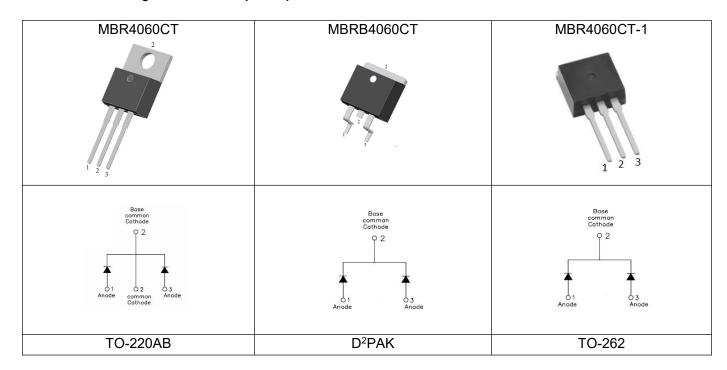
# MBR4060CT/MBRB4060CT-1 SCHOTTKY RECTIFIER

## **Features**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- · Terminals finish: Tin Lead-free plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



## Maximum Ratings@Tc=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	60	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=128°C, In DC	20(Per Leg) 40(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	400	А

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 20A, Pulse, T <sub>J</sub> = 25 °C	0.61	0.75	V
(Per Leg)*	$V_{F2}$	@ 20A, Pulse, T <sub>J</sub> = 125 °C	0.58	0.60	V
Reverse Current	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 °C	0.04	1.0	mA
(Per Leg)*	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 100 °C	7	75	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25  ^{\circ}C, f_{SIG} = 1MHz$	800	900	pF

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>θJC</sub>	DC operation	1.5	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

## **Tube Specification**

Device	Package	Weight	Shipping
MBR4060CT	TO-220AB	1.8g	50pcs / tube
MBRB4060CT	D <sup>2</sup> PAK	1.85g	800pcs / reel
MBR4060CT-1	TO-262	1.85g	50pcs / tube

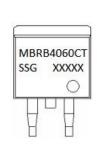
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

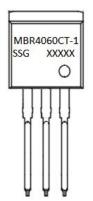
# **Tube Specification(TO-220AB/TO-262)**



## **Marking Diagram**







#### Where XXXXX is YYWWL

 MBR
 = Device Type

 B
 = Package type

 40
 = Forward Current (40A)

 60
 = Reverse Voltage (60V)

 CT-1
 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

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# **Ratings and Characteristics Curves**

Figure 1 Typical Forward Characteristics

101

102

100

0.0

0.2

0.4

0.6

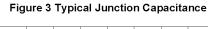
0.8

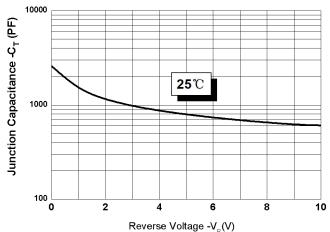
1.0

Forward Voltage -V<sub>F</sub>(V)

Figure 2 Typical Reverse Characteristics

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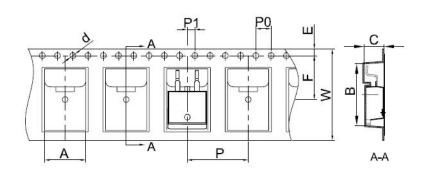
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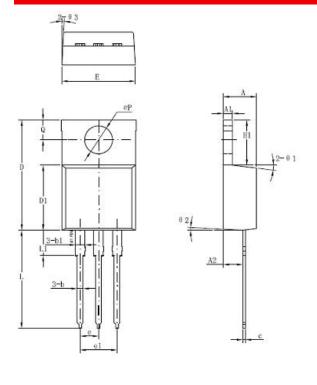


# Carrier Tape Specification D<sup>2</sup>PAK



Symbol	Millimeters		
	Min.	Max.	
Α	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

# **Mechanical Dimensions TO-220AB**



Symbol	Dimensions in millimeters		
	Min	Typical	Max
Α	3.56	-	4.83
A1	0.51	-	1.4
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E	9.65	-	10.67
е	-	2.54	-
e1	-	5.08	-
H1	5.84	-	6.86
L	12.7	-	14.73
L1	-	-	6.35
ФР	-	3.56	-
Q	2.54	-	3.43

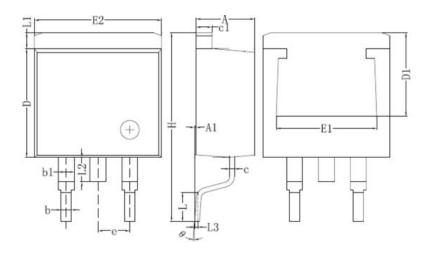
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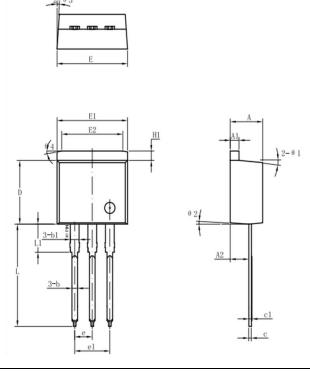


## Mechanical Dimensions D<sup>2</sup>PAK



0	Dimensions in millimeters		
Symbol	Min.	Max.	
Α	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
С	0.31	0.74	
c1	1.14	1.65	
D	8.38	9.65	
D1	6.4		
E1	6.22		
E2	9.65	10.67	
е	2.541	BSC	
Н	14.6	15.88	
L	1.78	2.8	
L1	-	1.68	
L2	-	2.2	
L3	0.255BSC		
Θ	0	8°	

# **Mechanical Dimensions TO-262**



Compleal	Millimeters			
Symbol	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
В	1.22	1.37	1.47	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	8.55	8.70	8.85	
E	10.01	10.16	10.31	
E1	9.88	10.08	10.28	
е		2.54		
e1		5.08		
H1	1.17	1.27	1.37	
L	13.00	13.86	14.08	
L1		3.8		
Θ1		5°		
Θ2		4°		
Θ3		4°		
Θ4		10°		

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# MBR4060CT MBRB4060CT MBR4060CT-1

### Technical Data Data Sheet N0178, Rev. A





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